Electronic Acknowledgement Receipt				
EFS ID:	1164143			
Application Number:	10598213			
Confirmation Number:	1211			
Title of Invention:	A BIPOLAR JUNCTION TRANSISTOR HAVING A HIGH GERMANIUM CONCENTRATION IN A SILICON GERMANIUM LAYER AND A METHOD FOR FORMING THE BIPOLAR JUNCTION TRANSISTOR			
First Named Inventor:	Michelle D. Griglione			
Customer Number:	47396			
Filer:	Greg H. Parker/Elizabeth Schumacher			
Filer Authorized By:	Greg H. Parker			
Attorney Docket Number:	GRIGLIONE 5			
Receipt Date:	21-AUG-2006			
Filing Date:				
Time Stamp:	16:26:13			
Application Type:	U.S. National Stage under 35 USC 371			
International Application Number:	PCT/US05/08212			

Payment information:

Submitted with Payment	yes
Payment was successfully received in RAM	\$2050
RAM confirmation Number	253
Deposit Account	082395

File Listing:

Document Number	Document Description	File Name	File Size(Bytes)	Multi Part	Pages
--------------------	----------------------	-----------	------------------	---------------	-------

1	Transmittal letter	Transmittal.pdf	116326	no	1
Warnings:				l	
Information:					i
2	Specification	Specification.pdf	679207	no	11
Warnings:					
Information:					
3	Claims	Claims.pdf	206130	no	4
Warnings:					
Information:					
4	Abstract	Abstract.pdf	25124	no	1
Warnings:					
Information:					
5	Drawings	Formal_Drawings.pdf	203880	no	9
Warnings:					
Information:					
6	Oath or Declaration filed	Declaration.pdf	117428	no	3
Warnings:				•	
Information:					ı
7	Information Disclosure Statement (IDS) Filed	IDS_Form.pdf	736289	no	5
Warnings:					
Information:					
8	Foreign Reference	EP0490111A1.pdf	1180022	no	16
Warnings:				·	
Information:					
9	Foreign Reference	EP0435135A1.pdf	629071	no	11
Warnings:			1	1	1
Information:					

10	Foreign Reference	EP0881669A1.pdf	1031120	no	25
Warnings:				I	L
Information:					
11	Foreign Reference	WO2005088721A1.pdf	1072534	no	28
Warnings:				I	l
Information:					
12	NPL Documents	Effects_of_Ge_Concentratio n.pdf	511539	no	3
Warnings:				1	<u> </u>
Information:					
13	NPL Documents	Chem_Mech_Polish.pdf	256888	no	3
Warnings:					
Information:					
14	NPL Documents	Dry_Thermal_Oxidation.pdf	702901	no	3
Warnings:					
Information:					
15	NPL Documents	Oxidation_Studies.pdf	1403477	no	5
Warnings:		1		I	I
Information:					
16	Fee Worksheet (PTO-875)	fee-info.pdf	8650	no	2
Warnings:					
Information:					
	Total Files Size (in bytes): 8880586				
			•		

This Acknowledgement Receipt evidences receipt on the noted date by the USPTO of the indicated documents, characterized by the applicant, and including page counts, where applicable. It serves as evidence of receipt similar to a Post Card, as described in MPEP 503.

New Applications Under 35 U.S.C. 111

If a new application is being filed and the application includes the necessary components for a filing date (see 37 CFR 1.53(b)-(d) and MPEP 506), a Filing Receipt (37 CFR 1.54) will be issued in due course and the date shown on this Acknowledgement Receipt will establish the filing date of the application.

National Stage of an International Application under 35 U.S.C. 371

If a timely submission to enter the national stage of an international application is compliant with the conditions of 35 U.S.C. 371 and other applicable requirements a Form PCT/DO/EO/903 indicating acceptance of the application as a national stage submission under 35 U.S.C. 371 will be issued in addition to the Filing Receipt, in due course.